

Features

- Fast switching
- Green Device Available
- Suit for 1.5V Gate Drive Applications

Application

- Notebook
- Load Switch
- Networking
- Hand-held Instruments

Package and Pin Configuration

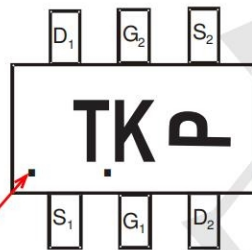
Circuit diagram

SOT363

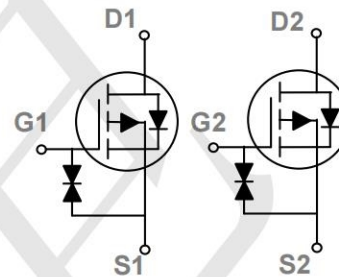


Top View

Marking:



Top View
Pin out



Absolute Maximum Ratings $T_C=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	-20	V
V_{GS}	Gate-Source Voltage	± 12	V
I_D	Drain Current – Continuous ($T_C=25^{\circ}\text{C}$)	-1.1	A
I_{DM}	Drain Current – Pulsed ¹	-2.2	A
P_D	Power Dissipation ($T_C=25^{\circ}\text{C}$)	280	mW
	Power Dissipation – Derate above 25°C	2.5	mW/ $^{\circ}\text{C}$
T_{STG}	Storage Temperature Range	-55 to 150	$^{\circ}\text{C}$
T_J	Operating Junction Temperature Range	-55 to 150	$^{\circ}\text{C}$

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JA}$	Thermal Resistance Junction to ambient	---	350	$^{\circ}\text{C}/\text{W}$

Electrical Characteristics ($T_J=25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=-250\mu A$	-20	---	---	V
$\Delta BV_{DSS}/\Delta T_J$	BV_{DSS} Temperature Coefficient	Reference to 25°C , $I_D=-1\text{mA}$	---	-0.01	---	$V/^\circ\text{C}$
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=-20V, V_{GS}=0V, T_J=25^\circ\text{C}$	---	---	-1	μA
		$V_{DS}=-16V, V_{GS}=0V, T_J=125^\circ\text{C}$	---	---	-10	μA
I_{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm 12V, V_{DS}=0V$	---	---	± 20	μA

On Characteristics

$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS}=-4.5V, I_D=-0.5A$	---	400	680	$m\Omega$
		$V_{GS}=-2.5V, I_D=-0.5A$	---	550		
		$V_{GS}=-1.8V, I_D=-0.1A$	---	750	1050	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}, I_D=-250\mu A$	-0.5	-0.7	1.0	V
$\Delta V_{GS(th)}$	$V_{GS(th)}$ Temperature Coefficient		---	3	---	$mV/^\circ\text{C}$

Dynamic and switching Characteristics

Q_g	Total Gate Charge ^{2,3}	$V_{DS}=-10V, V_{GS}=-4.5V, I_D=-1A$	---	0.5	nC
Q_{gs}	Gate-Source Charge ^{2,3}		---	0.28	
Q_{gd}	Gate-Drain Charge ^{2,3}		---	0.28	
$T_{d(on)}$	Turn-On Delay Time ^{2,3}	$V_{DD}=-10V, V_{GS}=-4.5V, R_G=6\Omega$ $I_D=-1A$	---	0.4	ns
T_r	Rise Time ^{2,3}		---	0.06	
$T_{d(off)}$	Turn-Off Delay Time ^{2,3}		---	0.02	
T_f	Fall Time ^{2,3}		---	0.8	
C_{iss}	Input Capacitance	$V_{DS}=-10V, V_{GS}=0V, F=1\text{MHz}$	---	55	pF
C_{oss}	Output Capacitance		---	6	
C_{riss}	Reverse Transfer Capacitance		---	4.5	

Drain-Source Diode Characteristics and Maximum Ratings

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{SD}	Diode Forward Voltage	$V_{GS}=0V, I_S=-0.2A, T_J=25^\circ\text{C}$	---	-0.75	-1.1	V

Characteristic Curves

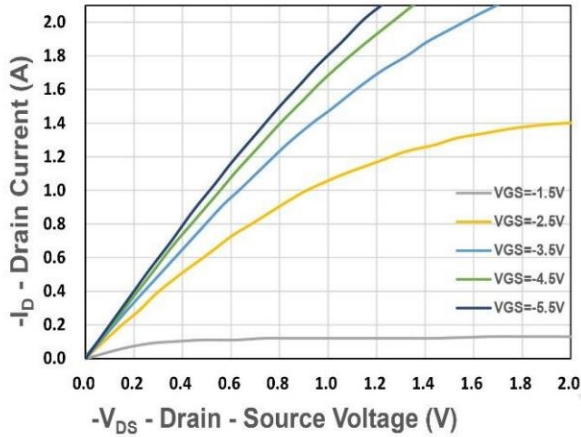


Figure 1. Output Characteristics

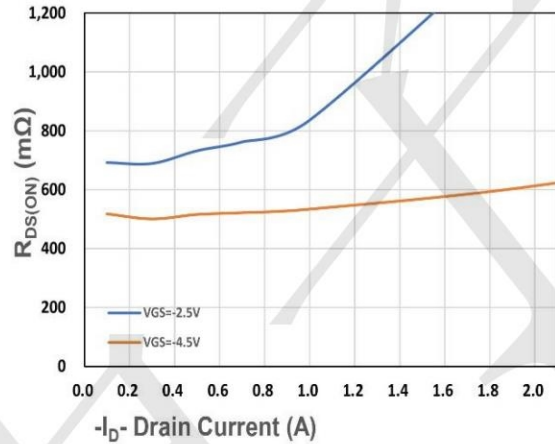


Figure 2. On-Resistance vs. I_D

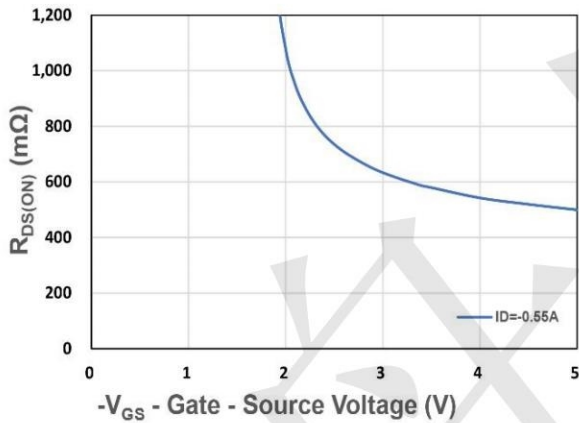


Figure 3. On-Resistance vs. V_{GS}

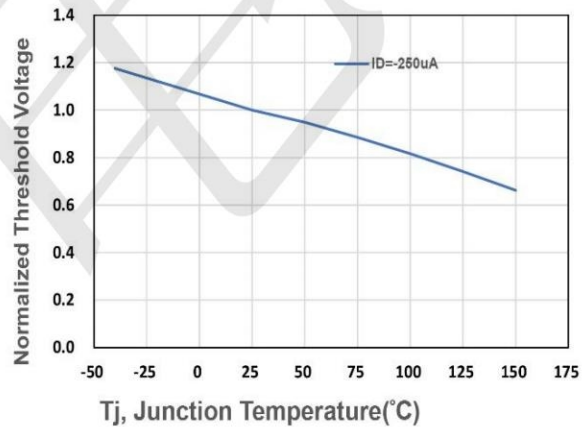


Figure 4. Gate Threshold Voltage

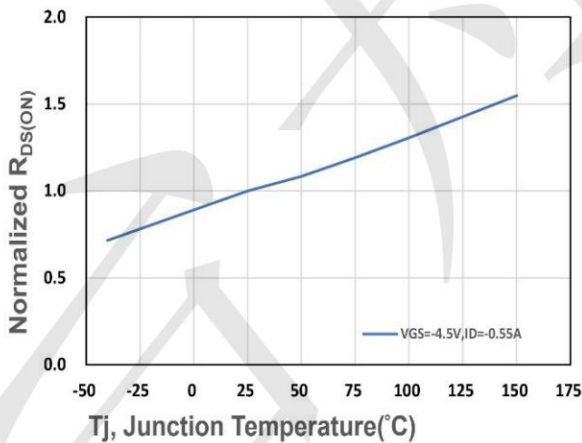


Figure 5. Drain-Source On Resistance

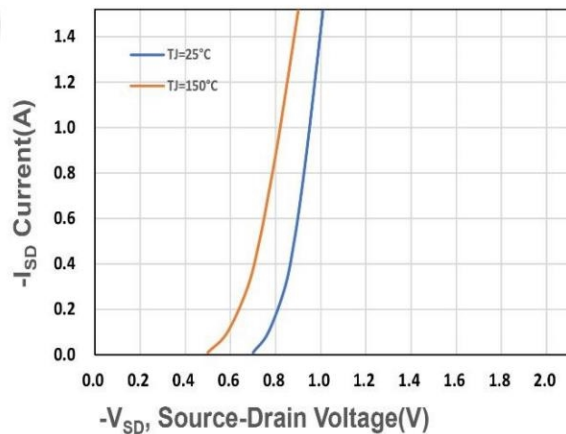


Figure 6. Source-Drain Diode Forward

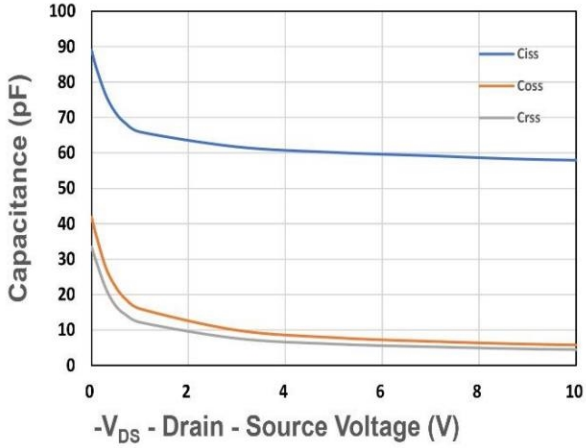


Figure 7. Capacitance

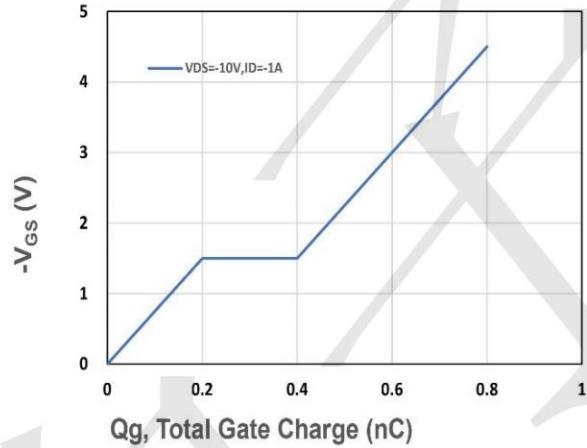


Figure 8. Gate Charge Characteristics

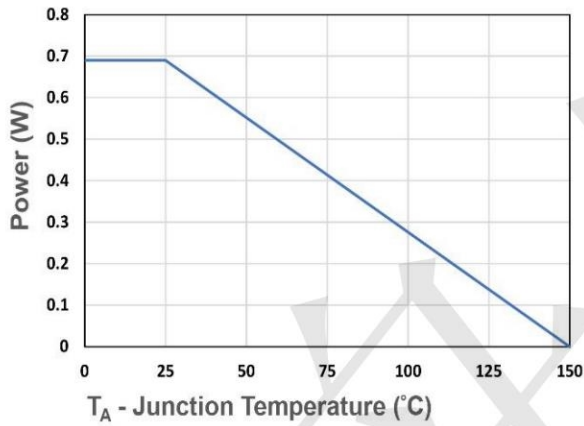


Figure 9. Power Dissipation

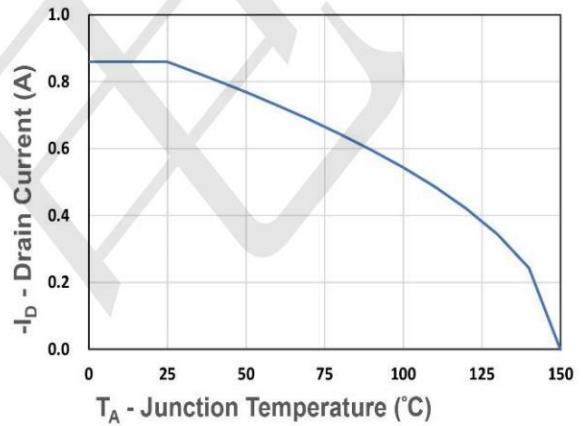


Figure 10. Drain Current

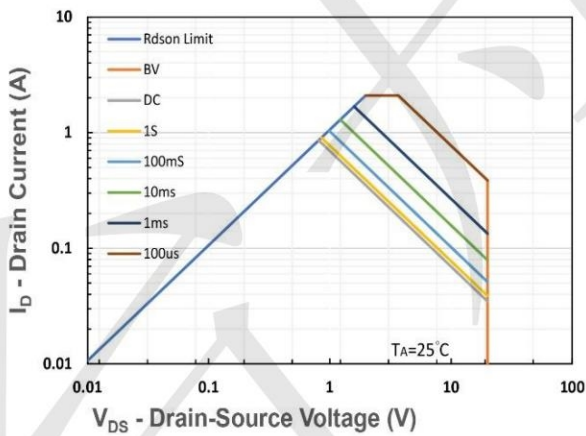


Figure 11. Safe Operating Area

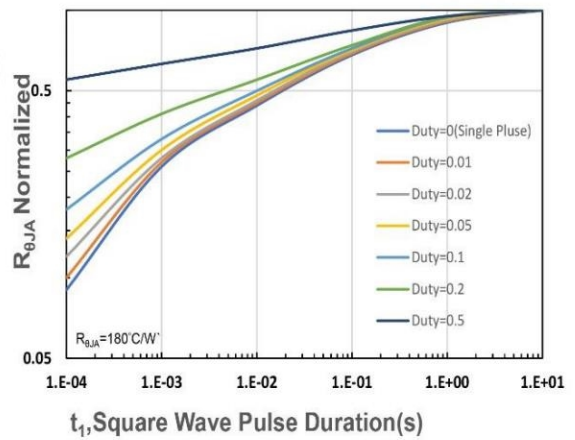
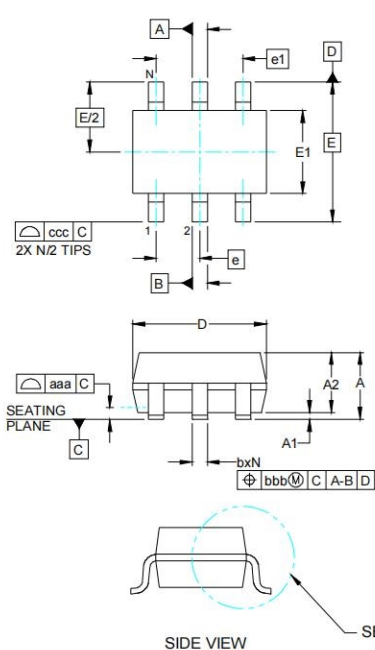
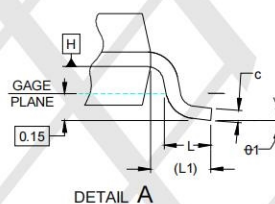


Figure 12. $R_{\theta JA}$ Transient Thermal Impedance

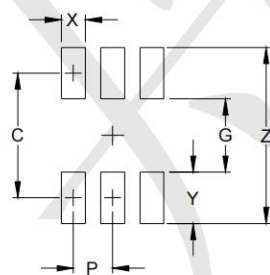
Outline Drawing - SOT-363(2.0X2.1)



DIM	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	-	-	.043	-	-	1.10
A1	.000	-	.004	0.00	-	0.10
A2	.028	.035	.039	0.70	0.90	1.00
b	.006	-	.012	0.15	-	0.30
c	.003	-	.009	0.08	-	0.22
D	.071	.079	.087	1.80	2.00	2.20
E1	.045	.049	.053	1.15	1.25	1.35
E	.083 BSC			2.10 BSC		
e	.026 BSC			0.65 BSC		
e1	.051			1.30 BSC		
L	.010	.014	.018	0.26	0.36	0.46
L1	(0.17)			(0.42)		
N	6			6		
$\theta 1$	0°	-	8°	0°	-	8°
aaa	.004			0.10		
bbb	.004			0.10		
ccc	.012			0.30		

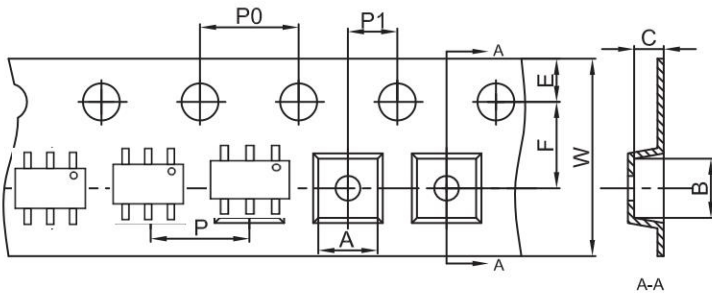


Land Pattern - SOT-363



DIM	DIMENSIONS	
	INCHES	MILLIMETERS
C	(.073)	(1.85)
G	.039	1.00
P	.026	0.65
X	.016	0.40
Y	.033	0.85
Z	.106	2.70

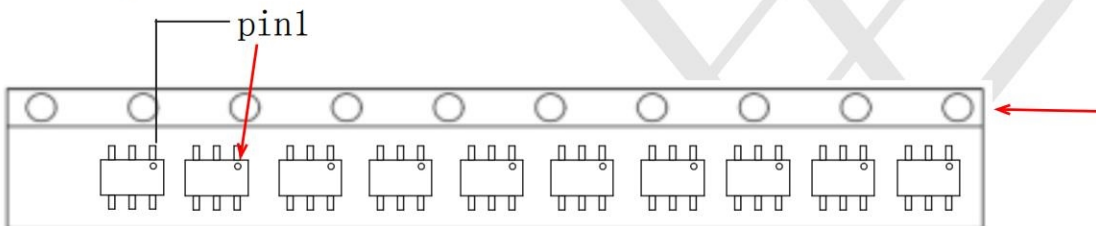
SOT-363 Embossed Carrier Tape



Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-363	2.25	2.55	1.20	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

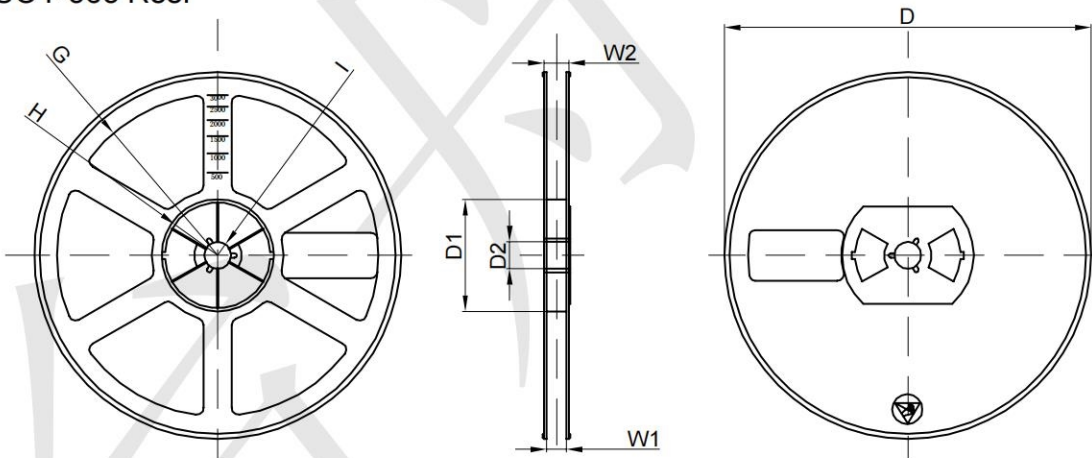
SOT-363 Tape Leader and Trailer

Package orientation in reel



Shipping: 3000 pcs / Tape & Reel

SOT-363 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 Inch	45,000 pcs	203×203×195	180,000 pcs	438×438×220	

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